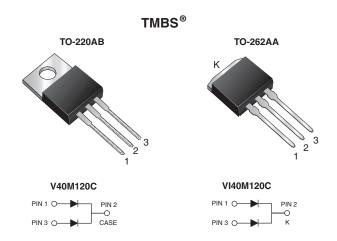


Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.46 \text{ V}$ at $I_F = 5 \text{ A}$



| PRIMARY CHARACTERISTICS | | | | | |
|---|--------------------|--|--|--|--|
| I _{F(AV)} | 2 x 20 A | | | | |
| V_{RRM} | 120 V | | | | |
| I _{FSM} | 250 A | | | | |
| V _F at I _F = 20 A | 0.64 V | | | | |
| T _J max. | 175 °C | | | | |
| Package | TO-220AB, TO-262AA | | | | |
| Diode variations | Common cathode | | | | |

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

High efficiency operation

COMPLIANT HALOGEN FREE

Solder dip 275 °C max. 10 s, per JESD 22-B106

 Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|------------|-----------------------------------|----------|-----------|------|
| PARAMETER | | SYMBOL | V40M120C | VI40M120C | UNIT |
| Maximum repetitive peak reverse voltage | | V_{RRM} | 120 | | V |
| Maximum average forward rectified current (fig. 1) | per device | I _{F(AV)} | 40 | | A |
| | per diode | | 20 | | |
| Peak forward surge current 8.3 ms single half sine-way superimposed on rated load per diode | ve | I _{FSM} | 250 | | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 | 000 | V/µs |
| Operating junction and storage temperature range | | T _J , T _{STG} | -40 to | +175 | °C |



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|-----------------------|-------------------------|-------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.54 | - | V | |
| | I _F = 10 A | | | 0.64 | - | | |
| | I _F = 20 A | | | 0.79 | 0.89 | | |
| | I _F = 5 A | T _A = 125 °C | | 0.46 | - | | |
| | I _F = 10 A | | | 0.54 | - | | |
| | $I_F = 20 \text{ A}$ | | | 0.64 | 0.72 | | |
| Reverse current per diode | V _R = 90 V | T _A = 25 °C | I _R (2) | 4 | - | μA | |
| | | T _A = 125 °C | | 3 | - | mA | |
| | I Vp = 120 V | T _A = 25 °C | | - | 500 | μA | |
| | | T _A = 125 °C | | 6 | 32 | mA | |

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 5 \text{ ms}$

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|------------|----------------------|----------|-----------|------|--|
| PARAMETER | | SYMBOL | V40M120C | VI40M120C | UNIT | |
| | per diode | В | 1.8 | | °C/W | |
| Typical thermal resistance (1) | per device | $R_{	heta JC}$ | 0.85 | | | |
| | per device | R _{0JA} (2) | 45 | 55 | | |

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient $dP_D/dT_J < 1/R_{\theta JA}$

(2) Free air, without heatsink

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|-----------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-220AB | V40M120C-M3/4W | 1.88 | 4W | 50/tube | Tube | |
| TO-262AA | VI40M120C-M3/4W | 1.45 | 4W | 50/tube | Tube | |

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

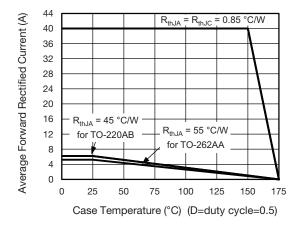


Fig. 1 - Maximum Forward Current Derating Curve

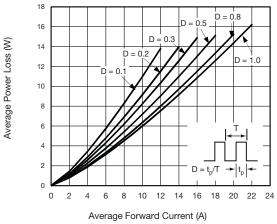


Fig. 2 - Forward Power Loss Characteristics Per Diode

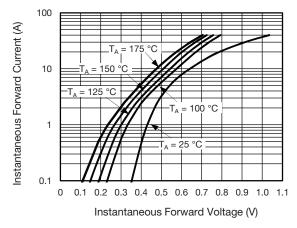


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

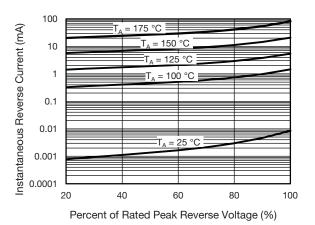


Fig. 4 - Typical Reverse Characteristics Per Diode

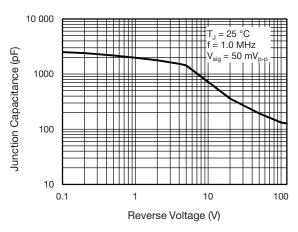


Fig. 5 - Typical Junction Capacitance Per Diode

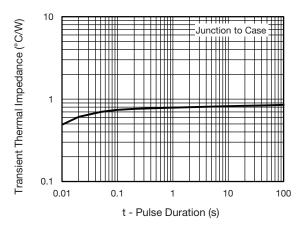
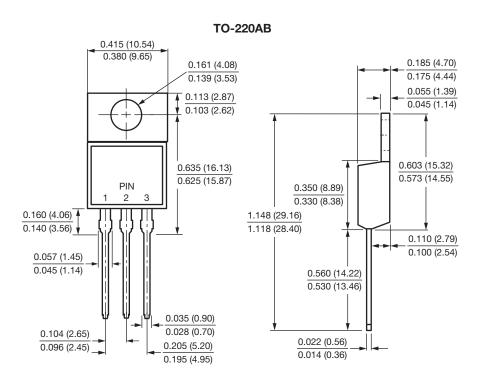


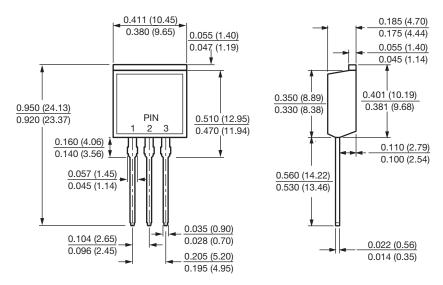
Fig. 6 - Typical Transient Thermal Impedance Per Diode

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA





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